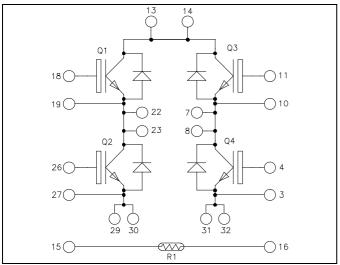
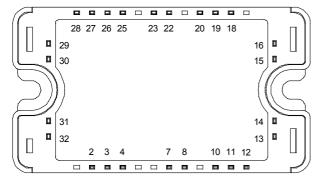


Full - Bridge NPT IGBT Power Module

 $V_{CES} = 600V$ $I_{C} = 30A$ @ $T_{C} = 80^{\circ}C$





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
 - Symmetrical design
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration
- Internal thermistor for temperature monitoring

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS compliant

Absolute maximum ratings

| Symbol | Parameter | | Max ratings | Unit |
|-------------|---------------------------------------|---------------------|-------------|------|
| V_{CES} | Collector - Emitter Breakdown Voltage | | 600 | V |
| Ţ | Continuous Collector Current | $T_C = 25^{\circ}C$ | 42 | |
| $I_{\rm C}$ | Continuous Conector Current | $T_C = 80$ °C | 30 | Α |
| I_{CM} | Pulsed Collector Current | $T_C = 25^{\circ}C$ | 100 | |
| V_{GE} | Gate – Emitter Voltage | | ±20 | V |
| P_{D} | Maximum Power Dissipation | $T_C = 25^{\circ}C$ | 140 | W |
| RBSOA | Reverse Bias Safe Operating Area | $T_j = 125$ °C | 60A@500V | |

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|---------------------|-------------------------------------|--------------------------------|---------------------|-----|-----|------|------|
| T | Zero Gate Voltage Collector Current | $V_{GE} = 0V$ | $T_j = 25^{\circ}C$ | | | 250 | μA |
| I _{CES} | Zero Gate voltage Collector Current | $V_{CE} = 600V$ | $T_j = 125$ °C | | | 500 | μΑ |
| V | Collector Emitter on Voltage | $V_{GE} = 15V$ | $T_j = 25$ °C | 1.7 | 2.0 | 2.45 | V |
| V _{CE(on)} | Confector Emitter on Voltage | $I_C = 30A$ | $T_j = 125$ °C | | 2.2 | | V |
| $V_{GE(th)}$ | Gate Threshold Voltage | $V_{GE} = V_{CE}, I_C = 1mA$ | | 4 | | 6 | V |
| I_{GES} | Gate – Emitter Leakage Current | $V_{GE} = 20V$, $V_{CE} = 0V$ | | | | 400 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Тур | Max | Unit |
|------------------|------------------------------|-----------------------------------|----------------|-----|------|-----|------|
| Cies | Input Capacitance | $V_{GE} = 0V$ | | | 1350 | | |
| C_{oes} | Output Capacitance | $V_{CE} = 25V$ | | | 193 | | pF |
| C_{res} | Reverse Transfer Capacitance | f = 1MHz | | 120 | | | |
| Q_g | Total gate Charge | $V_{GE} = 15V$ $V_{Bus} = 300V$ | | | 99 | | nC |
| Q_{ge} | Gate – Emitter Charge | | | | 10 | | |
| Q_{gc} | Gate – Collector Charge | $I_C = 30A$ | | | 60 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switch | ning (25°C) | | 30 | | |
| $T_{\rm r}$ | Rise Time | $V_{GE} = 15V$ | | | 12 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $V_{Bus} = 400V$ $I_{C} = 30A$ | | 80 | | ns | |
| T_{f} | Fall Time | $R_G = 6.8\Omega$ | | 15 | | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive Switch | | 32 | | | |
| $T_{\rm r}$ | Rise Time | $V_{GE} = 15V$ | | | 12 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $V_{Bus} = 400V$ $I_C = 30A$ | | | 90 | | ns |
| $T_{\rm f}$ | Fall Time | $R_G = 6.8\Omega$ | | | 21 | | |
| Eon | Turn-on Switching Energy | $V_{GE} = 15V$ $V_{Bus} = 400V$ | $T_j = 125$ °C | | 0.3 | | |
| E _{off} | Turn-off Switching Energy | $I_C = 30A$ $R_G = 6.8\Omega$ | $T_j = 125$ °C | | 0.8 | | mJ |

Reverse diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | Min | Typ | Max | Unit | |
|------------------|---|-----------------------------|------------------------|-----|-----|------|-----|
| V_{RRM} | Maximum Peak Repetitive Reverse Voltage | | | 600 | | | V |
| т | Maximum Reverse Leakage Current | V _R =600V | $T_j = 25$ °C | | | 150 | ۸ |
| I_{RM} | | V R-000 V | $T_j = 125$ °C | | | 500 | μA |
| I_{F} | DC Forward Current | | $Tc = 80^{\circ}C$ | | 15 | | A |
| | | $I_F = 15A$ | | | 1.6 | 1.8 | |
| $V_{\rm F}$ | Diode Forward Voltage | $I_F = 30A$ | | | 1.9 | | V |
| | | $I_F = 15A$ | $T_j = 125$ °C | | 1.4 | | |
| t_{rr} | Reverse Recovery Time | $I_F = 15A$ $V_R = 400V$ | $T_j = 25$ °C | | 40 | | ns |
| c _{rr} | Reverse Recovery Time | | $T_{j} = 125^{\circ}C$ | | 150 | | 115 |
| Q _{rr} | Reverse Recovery Charge | $di/dt = 200A/\mu s$ | $T_j = 25$ °C | | 95 | | пC |
| | | | $T_j = 125$ °C | | 520 | | 110 |



 $Temperature \ sensor \ NTC \ (see \ application \ note \ APT0406 \ on \ www.microsemi.com \ for \ more \ information).$

| Symbol | Characteristic | Min | Тур | Max | Unit |
|-----------------|-----------------------------|-----|------|-----|------|
| R ₂₅ | Resistance @ 25°C | | 50 | | kΩ |
| B 25/85 | $T_{25} = 298.15 \text{ K}$ | | 3952 | | K |

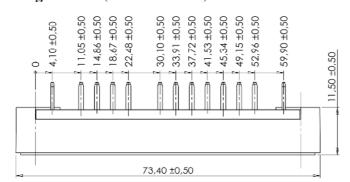
$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

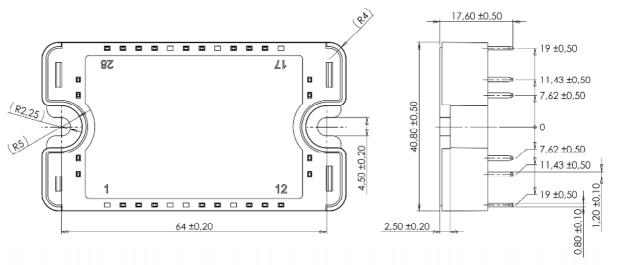
$$R_{T}: \text{ Thermistor value at T}$$

Thermal and package characteristics

| Symbol | Characteristic | | | Min | Тур | Max | Unit |
|-------------------|---|-------------|-------|------|-----|-----|--------------|
| R_{thJC} | Junction to Case Thermal Resistance | | IGBT | | | 0.9 | °C/W |
| | | | Diode | | | 2.0 | C/ VV |
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | 4000 | | | V |
| T_{J} | Operating junction temperature range -40 150 | | | | | | |
| T_{STG} | Storage Temperature Range | | -40 | | 125 | °C | |
| $T_{\rm C}$ | Operating Case Temperature | | | -40 | | 100 | |
| Torque | Mounting torque | To heatsink | M4 | 2 | | 3 | N.m |
| Wt | Package Weight | | • | | | 110 | g |

SP3 Package outline (dimensions in mm)

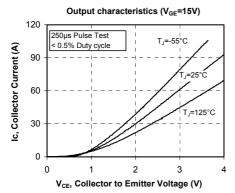


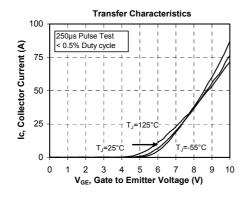


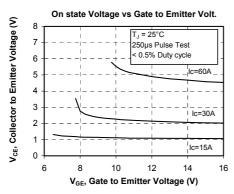
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

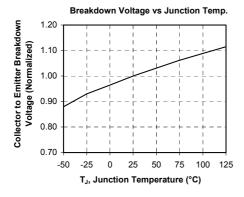


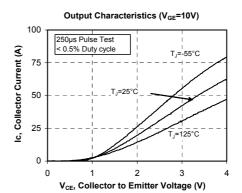
Typical Performance Curve

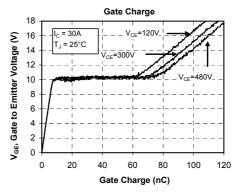


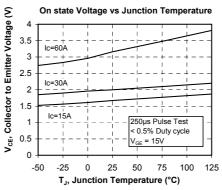


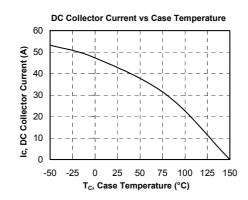




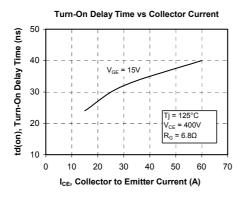


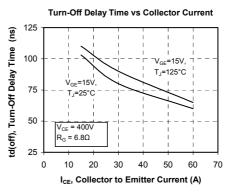


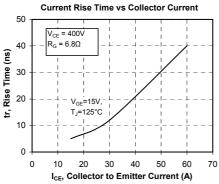


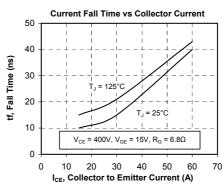


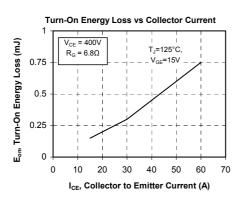


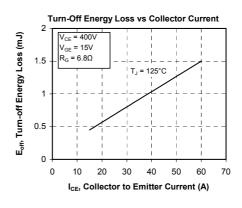


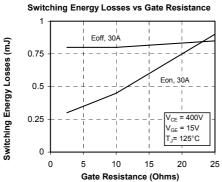


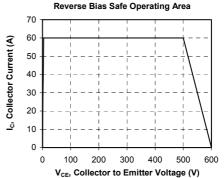






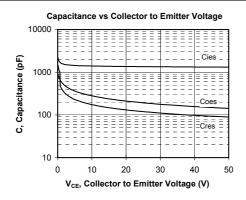


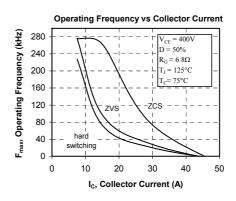


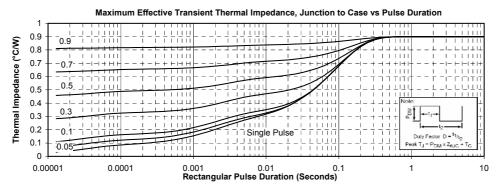


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